

Continuous Tuning of Electronic Correlations by Alkali Adsorption on Layered 1T-TaS₂

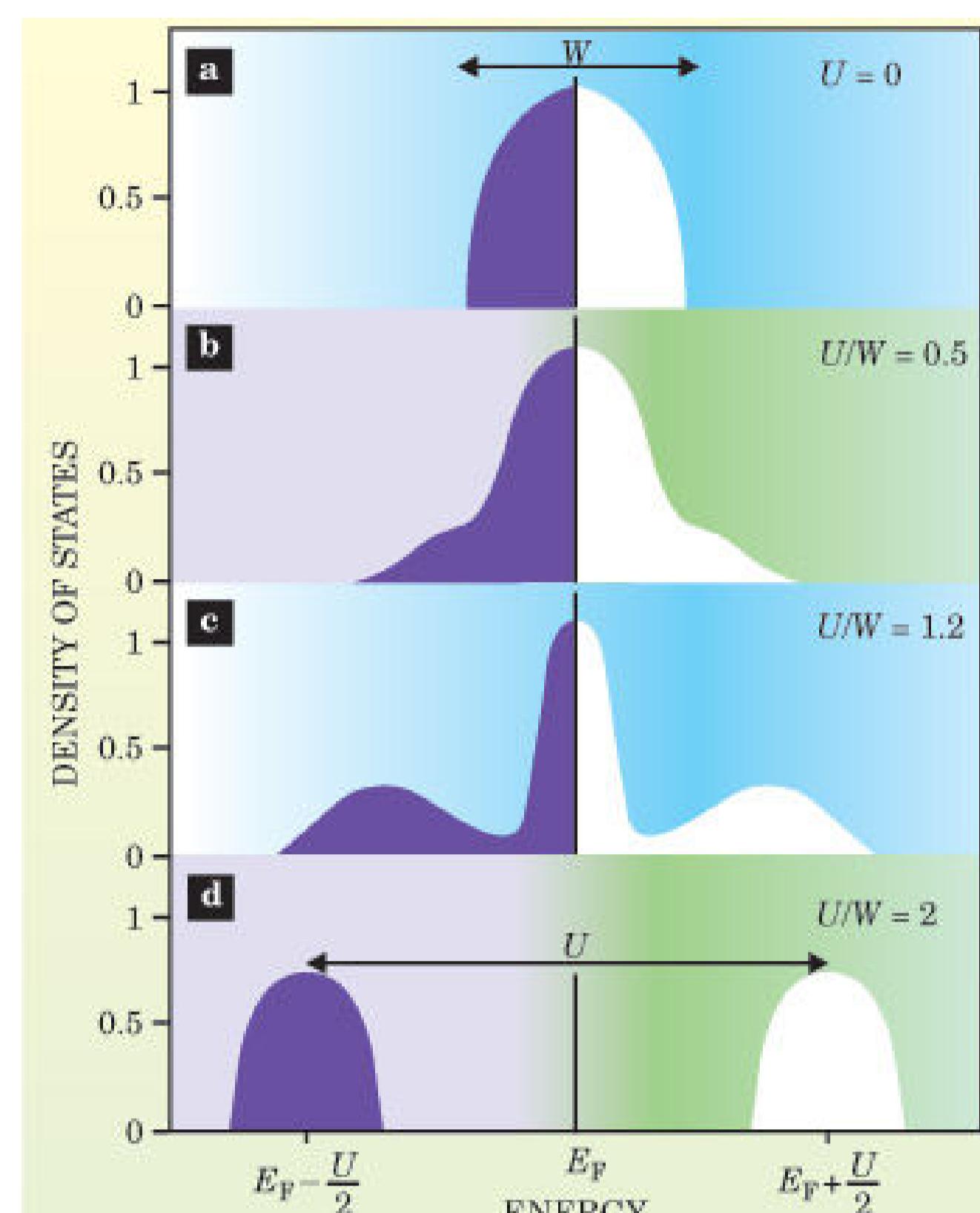
C | A | U

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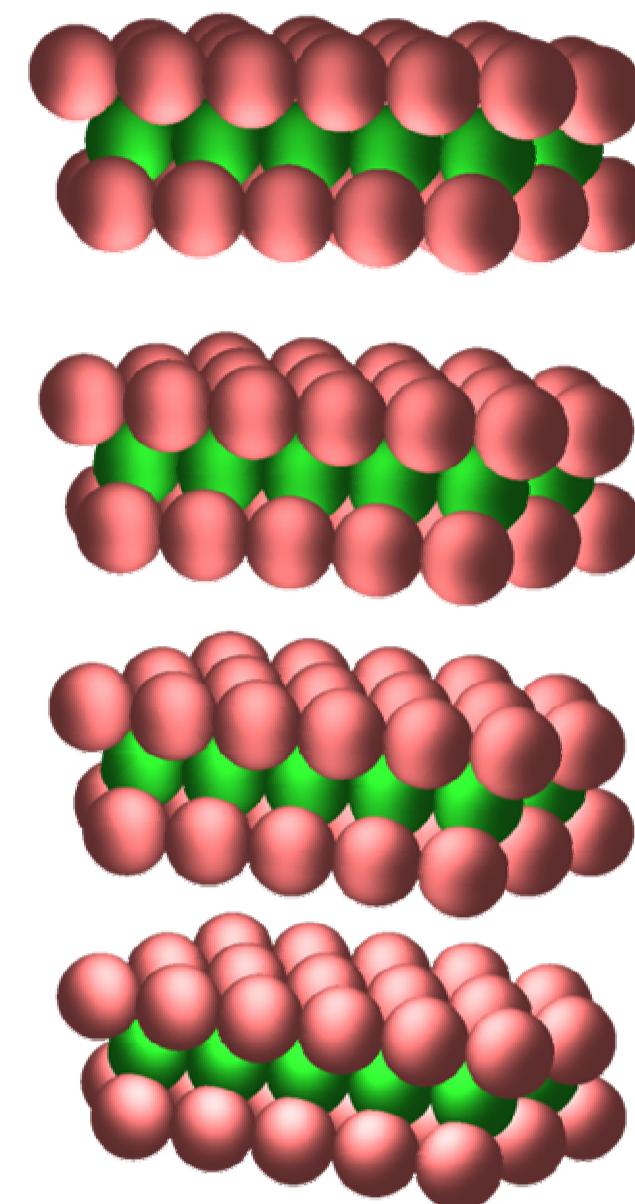
Motivation

Measure A(\mathbf{k}, ω) while tuning U / W

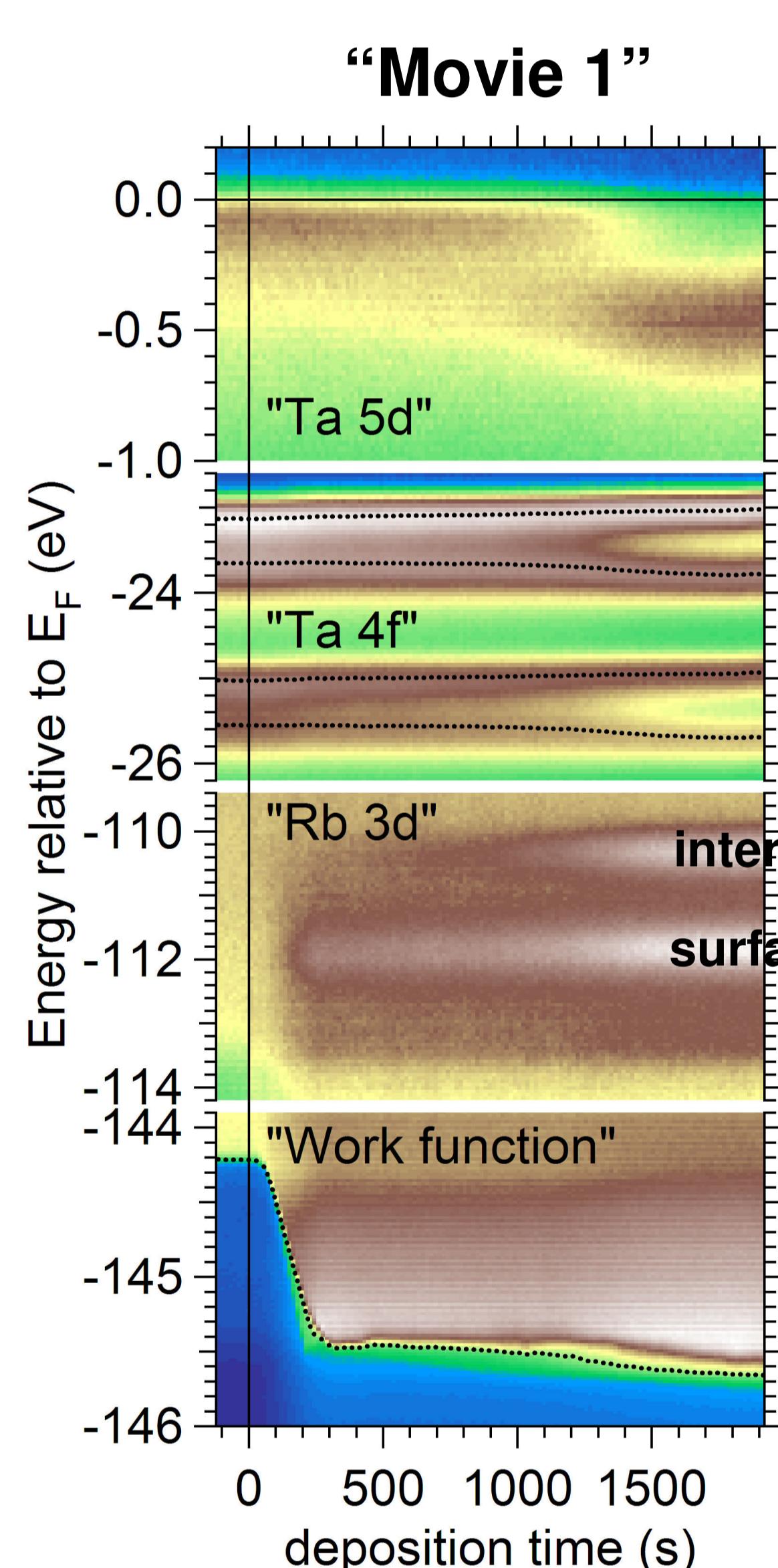
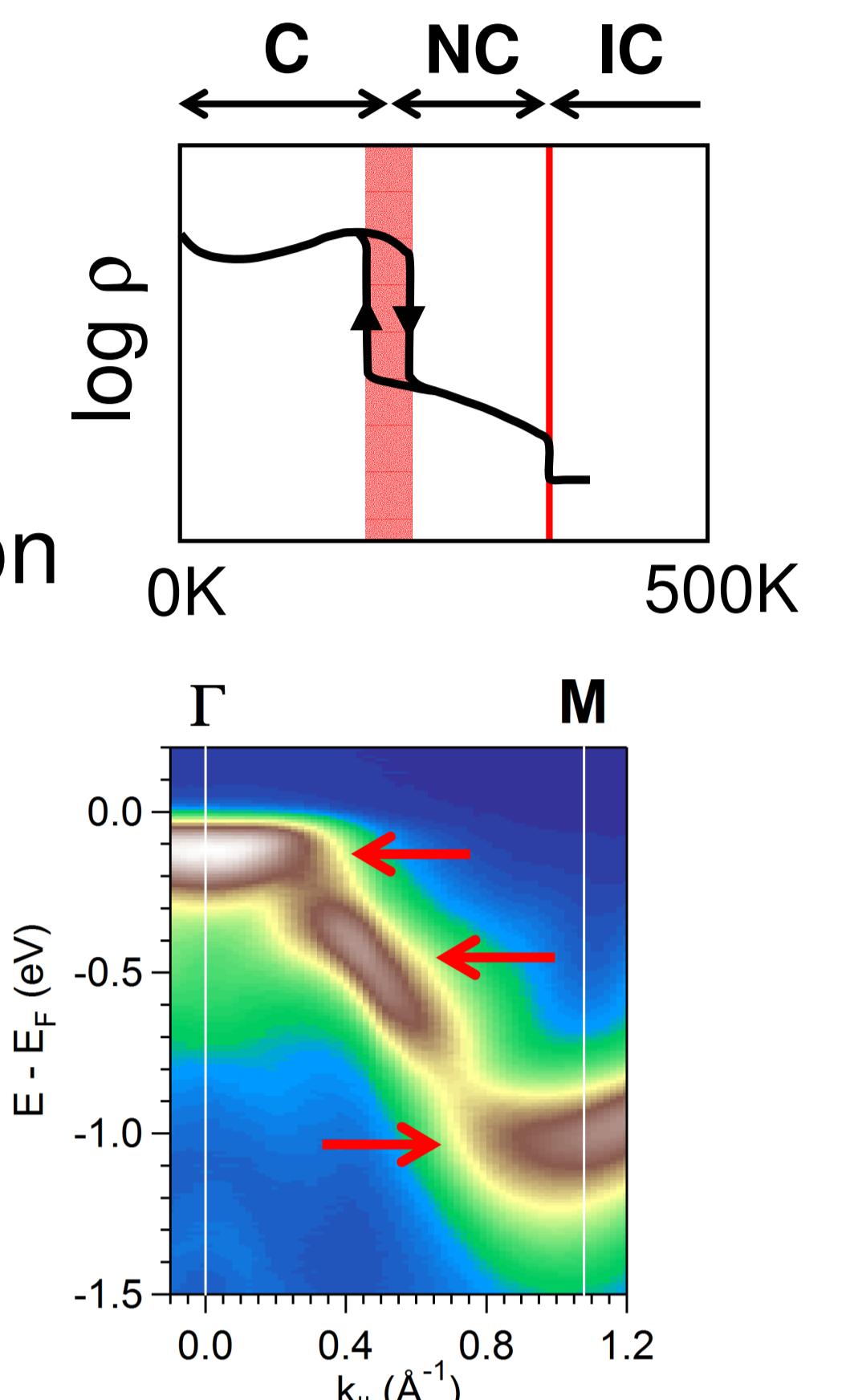
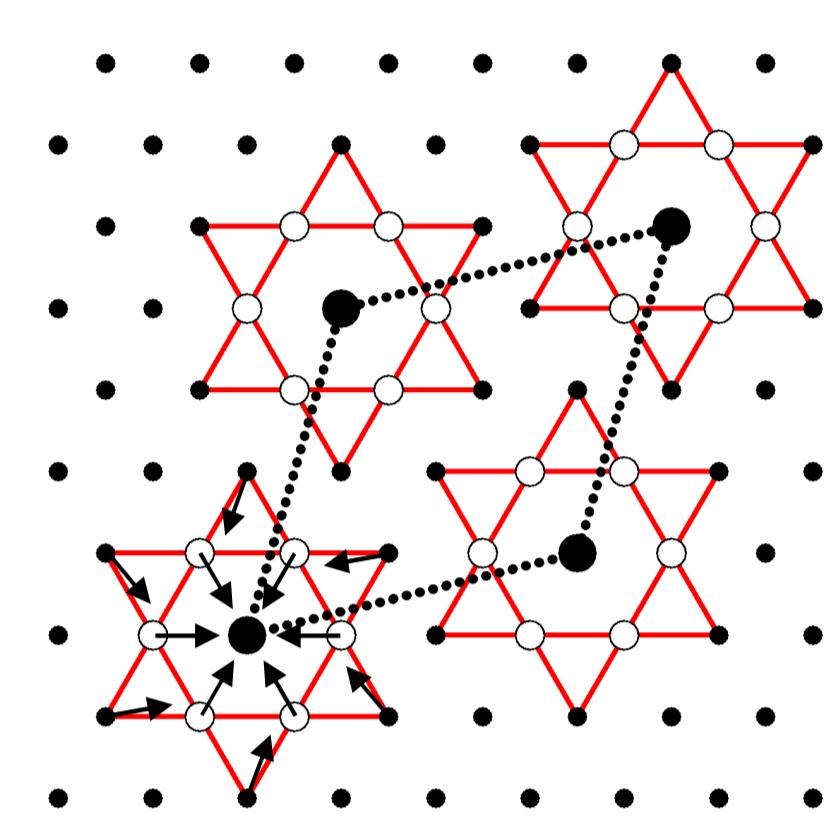
- hydrostatic pressure
- chemical composition
- alkali adsorption on layered crystals
(charge transfer, CDW, intercalation, ...)

Kotliar & Vollhardt,
Physics Today 3, 53 (2004)

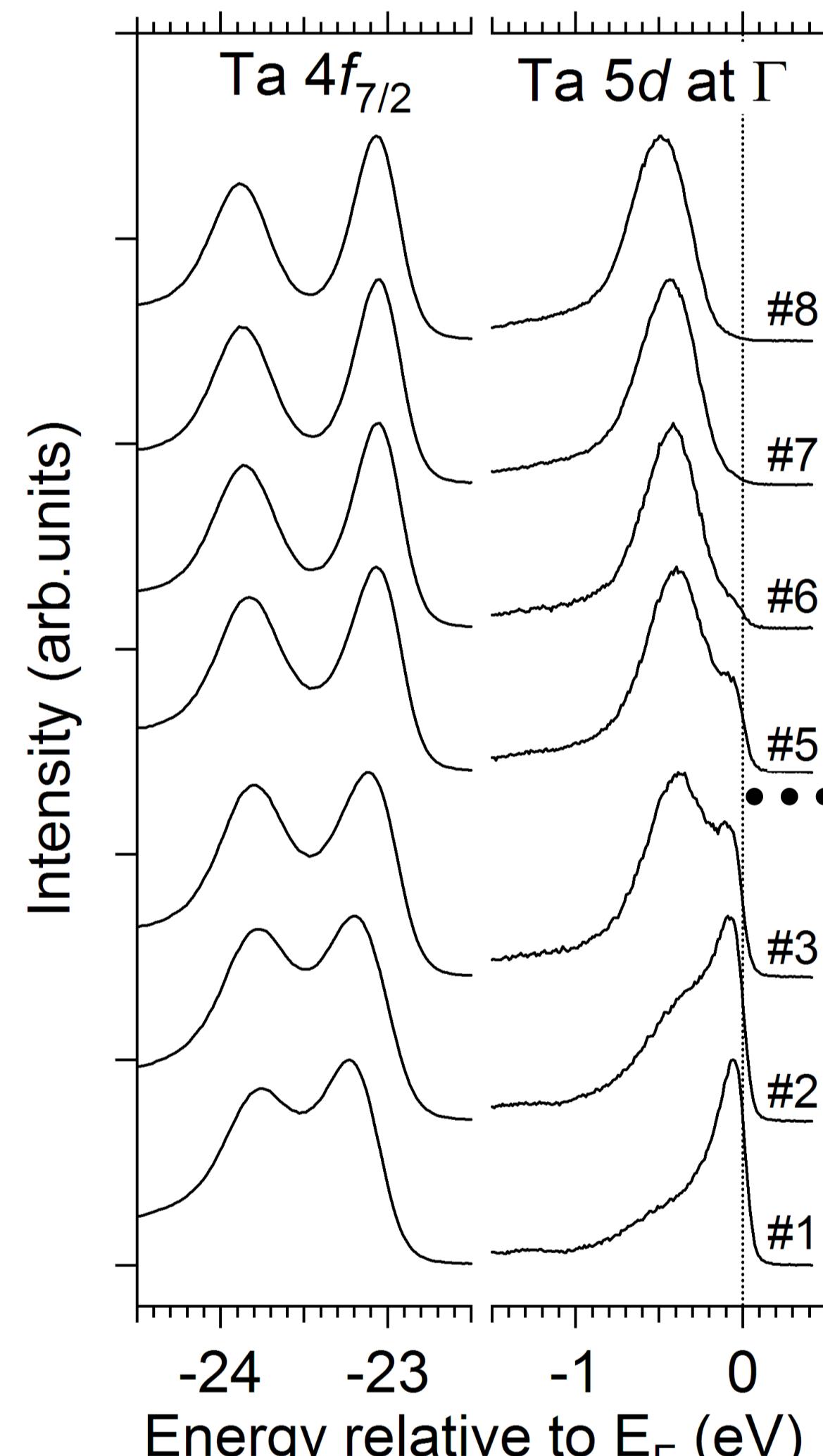
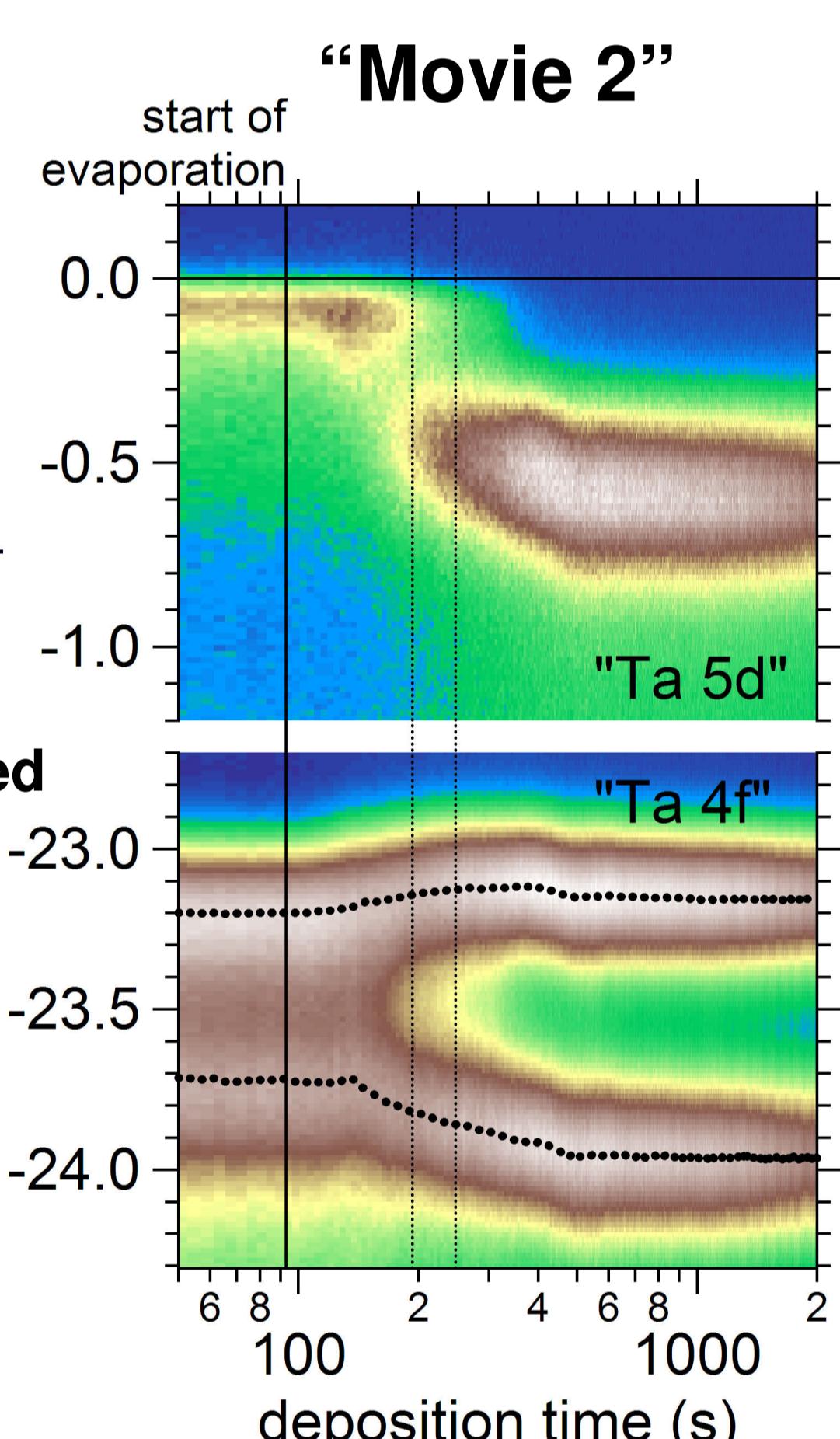
1T-TaS₂



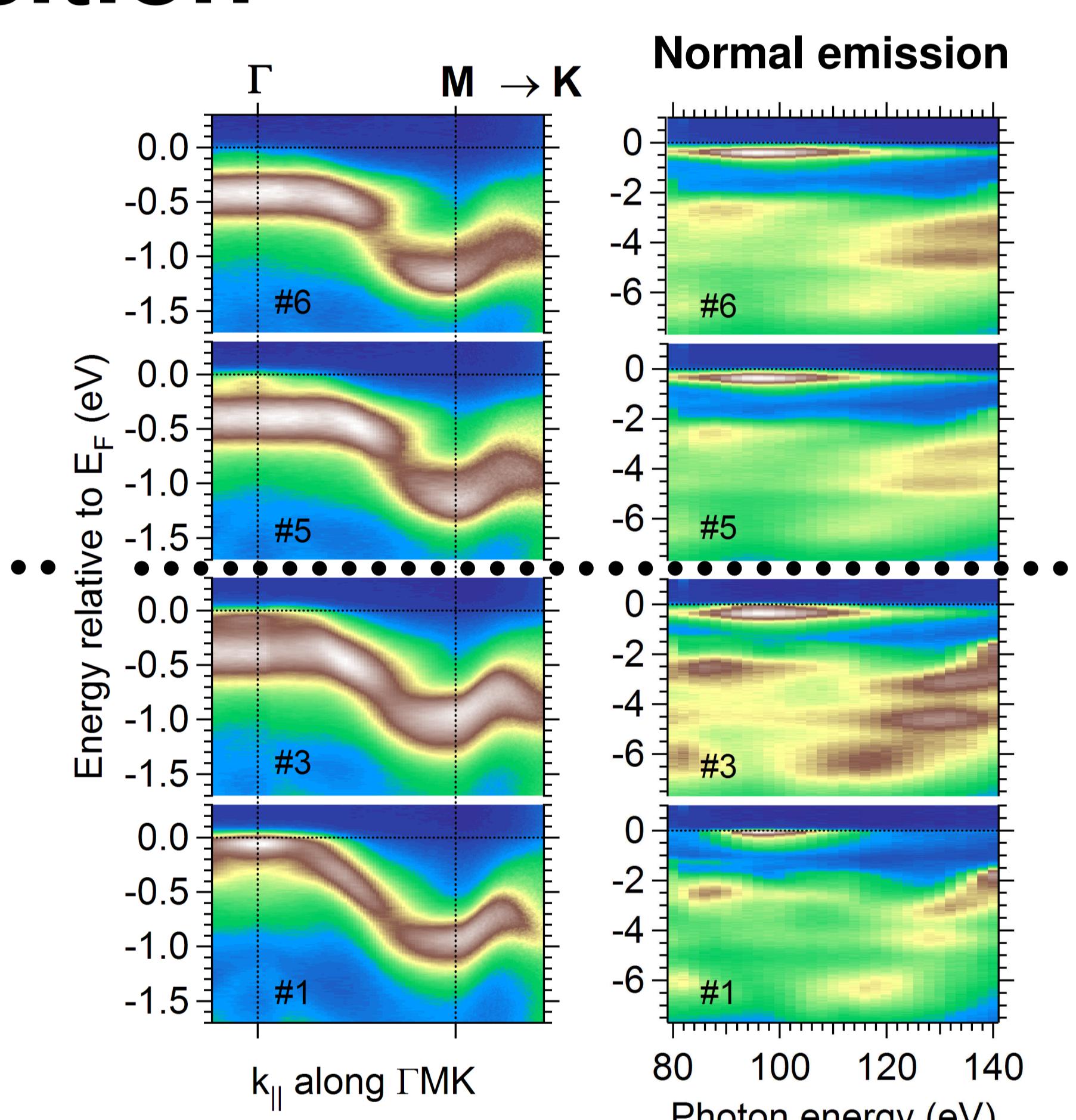
- $\sqrt{13} \times \sqrt{13}$ CDW
- Mott–Hubbard gap
- Anderson localization



Spectroscopy during Rb deposition

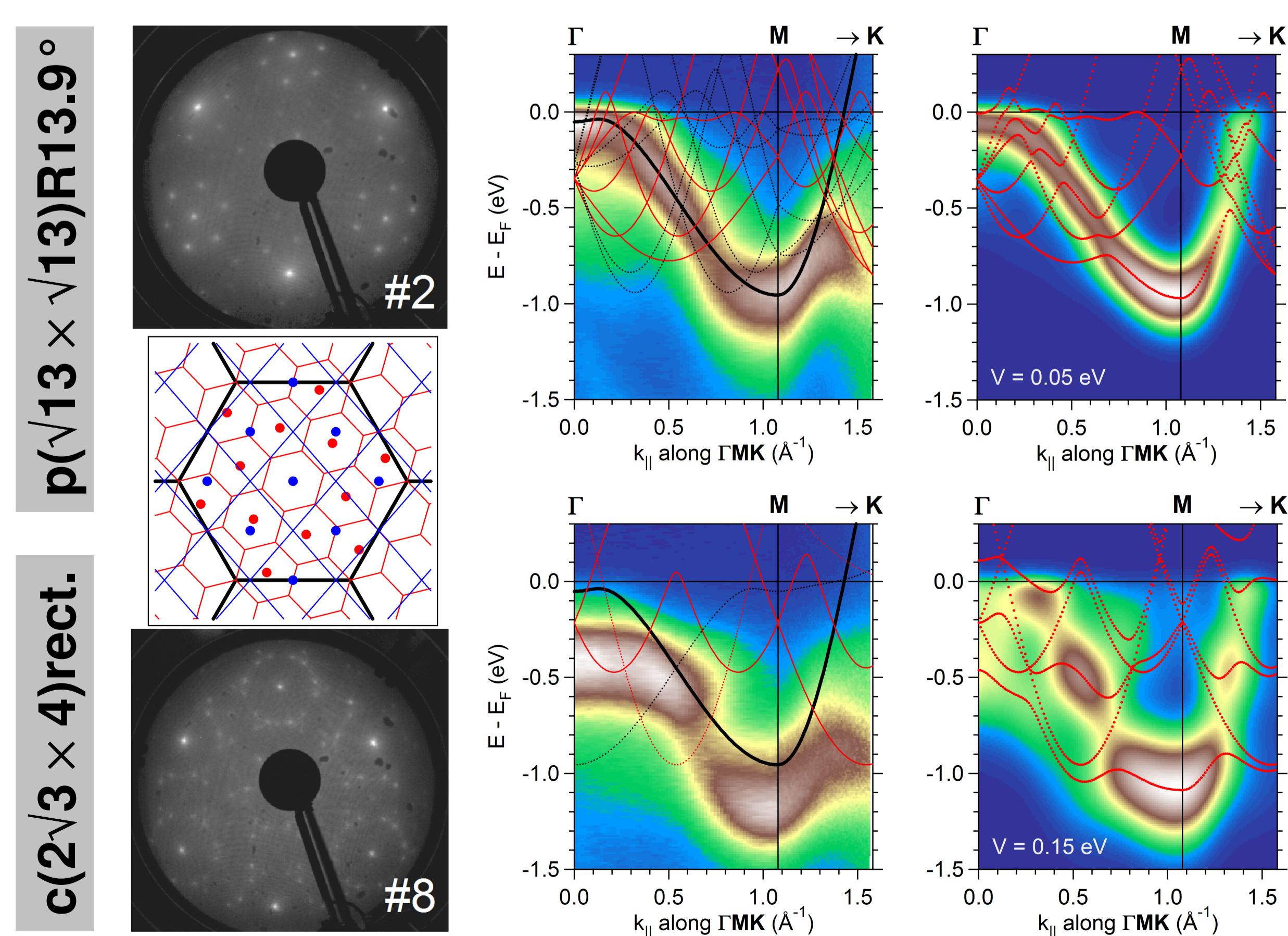


c(2 $\sqrt{3} \times 4$)rect.



Experiment:
ARPES @ "ESF"/BL7 @ ALS
 $h\nu = 96$ eV (198.5 eV), T = 300 K

Tight-binding simulation



Smith *et al.*, J. Phys. C.: Solid State Phys. 18, 3175 (1985)
Aiura *et al.*, Phys. Rev. B 69, 245123 (2004)

Results & discussion

Rb deposition on 1T-TaS₂:

- Metal–insulator transition (Ta 5d)
 - Mott–Hubbard type + e–ph interaction
- Modification of CDW:
 - Wave vector: $\sqrt{13}$ a \rightarrow $\sqrt{7}$ a (LEED)
 - Amplitude \sim (Ta 4f splitting, Ta 5d kinks)
- Rb adsorption + intercalation (Rb 3d)

Effects on critical parameters:

- Band filling: $n \approx 1 \approx \text{const.}$
- Correlation energy: $U \approx 0.8$ eV $\approx \text{const.}$
- Bandwidth: $W_{||} \uparrow (?)$, $W_{\perp} \downarrow (!)$

Questions:

- Why change of CDW?
- Role of electron–phonon interaction?